

HIGH PERFORMANCE CURRENT MODE PWM CONTROLLER

NOT FOR NEW DESIGN

1 FEATURES

- TRIMMED OSCILLATOR DISCHARGE CURRENT
- CURRENT MODE OPERATION TO 500kHz AUTOMATIC FEED FORWARD COMPENSATION
- LATCHING PWM FOR CYCLE-BY-CYCLE CURRENT LIMITING
- INTERNALLY TRIMMED REFERENCE WITH UNDERVOLTAGE LOCKOUT
- HIGH CURRENT TOTEM POLE OUTPUT UNDERVOLTAGE LOCKOUT WITH HYSTERESIS
- LOW START-UP CURRENT (< 0.5mA) DOUBLE PULSE SUPPRESSION

2 DESCRIPTION

The UC384xA family of control ICs provides the necessary features to implement off-line or DC to DC fixed frequency current mode control schemes with a minimal external parts count. Internally implemented circuits include a trimmed oscillator for precise DUTY CYCLE CONTROL under voltage lockout featuring start-up current less than 0.5mA, a precision reference trimmed for accuracy at the error amp input, logic to insure latched operation, a PWM comparator which also provides current limit control, and a totem pole output stage designed to source or sink high peak current. The output stage, suitable for driving in-Channel MOSFETs, is low in the off-stale.

Figure 1. Package

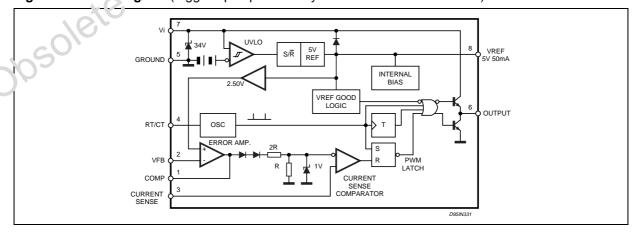


Table 1. Order Codes

Part Number	Package
UC2842AD1; UC3842AD1; UC2843AD1; UC3843AD1; UC2844AD1; UC3844AD1; UC2845AD1; UC3845AD1	SC-5
UC2842AN; UC3842AN; UC2843AN; UC3843AN; UC2844AN; UC3844AN; UC2845AN; UC3845AN	DIP-8

Difference: ceaween members of this family are the ur der-voltage lockout thresholds and maximum outy cycle ranges. The UC3842A and UC3844A have UVLO thresholds of 16V (on) and 10V (off), ideally suited off-line applications The corresponding thresholds for the UC3843A and UC3845A are 8.5 V and 7.9V. The UC3842A and UC3843A can operate to duty cycles approaching 100%. A range of the zero to < 50 % is obtained by the UC3844A and UC3845A by the addition of an internal toggle flip flop which blanks the output off every other clock cycle.

Figure 2. Block Diauram (toggle flip flop used only in UC3844A and UC3845A)



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Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
Vi	Supply Voltage (low impedance source)	30	V
Vi	Supply Voltage (li < 30mA)	Self Limiting	
Io	Output Current	±1	Α
Eo	Output Energy (capacitive load)	5	μJ
	Analog Inputs (pins 2, 3)	- 0.3 to 5.5	V
	Error Amplifier Output Sink Current	10	mA
P _{tot}	Power Dissipation at T _{amb} ≤ 25 °C (DIP-8)	1.25	W
P _{tot}	Power Dissipation at T _{amb} ≤ 25 °C (SO-8)	800	mW
T _{stg}	Storage Temperature Range	- 65 to 150	°C
TJ	Junction Operating Temperature	- 40 to 150	°C
TL	Lead Temperature (soldering 10s)	300	°C

^{*} All voltages are with respect to pin 5, all currents are positive into the specified terminal.

Figure 3. DIP-8/SO-8 Pin Connection (Top view)

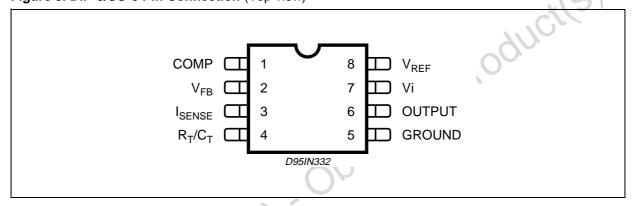


Table 3. Pin Description

N°	Pin	Function
1	COMP	This pin is the Error Amplifier output and is made available for loop compensation.
2	V _{FB}	This is the inverting input of the Error Amplifier. It is normally connected to the switching power supply output through a resistor divider.
3	ISENSE	A voltage proportional to inductor current is connected to this input. The PWM uses this information to terminate the output switch conduction.
4	R _T /C _T	The oscillator frequency and maximum Output duty cycle are programmed by connecting resistor R_T to V_{ref} and cpacitor C_T to ground. Operation to 500kHz is possible.
5	GROUND	This pin is the combined control circuitry and power ground.
6	OUTPUT	This output directly drives the gate of a power MOSFET. Peak currents up to 1A are sourced and sunk by this pin.
7	V_{CC}	This pin is the positive supply of the control IC.
8	V _{ref}	This is the reference output. It provides charging current for capacitor C _T through resistor R _T .

Table 4. Thermal Data

Symbol	Parameter	DIP-8	SO-8	Unit
R _{th j-amb}	Thermal Resistance Junction-ambient Max.	100	150	°C/W

Table 5. Electrical Characteristcs

([note 1] Unless otherwise stated, these specifications apply for -25 < T_{amb} < 85°C for UC284XA; 0 < T_{amb} < 70°C for UC384XA; V_i = 15V (note 5); R_T = 10K; C_T = 3.3nF)

0	D	To at Oo will the m	UC284XA			UC384XA			Unit
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
REFERE	ICE SECTION		•		•			•	
V _{REF}	Output Voltage	$T_j = 25$ °C $I_0 = 1$ mA	4.95	5.00	5.05	4.90	5.00	5.10	V
ΔV_{REF}	Line Regulation	$12V \leq V_i \leq 25V$		2	20		2	20	mV
ΔV_{REF}	Load Regulation	$1 \le I_0 \le 20 \text{mA}$		3	25		3	25	mV
$\Delta V_{REF}/\Delta T$	Temperature Stability	(Note 2)		0.2			0.2		mV/°C
	Total Output Variation	Line, Load, Temperature	4.9		5.1	4.82		5.18	V
e _N	Output Noise Voltage	$\begin{array}{l} 10 \text{Hz} \leq \text{f} \leq 10 \text{KHz} \\ \text{T}_{\text{j}} = 25^{\circ}\text{C} \text{ (note 2)} \end{array}$		50			50		μV
	Long Term Stability	Tamb = 125°C, 1000Hrs (note 2)		5	25	00	5	25	mV
Isc	Output Short Circuit		-30	-100	-180	-30	-100	-180	mA
OSCILLA	TOR SECTION		ı	v. O					
fosc	Frequency	T _j = 25°C	47	52	57	47	52	57	KHz
$\Delta f_{OSC}/\Delta V$	Frequency Change with Volt.	V _{CC} = 12V to 25V		0.2	1	_	0.2	1	%
$\Delta V_{REF}/\Delta T$	Frequency Change with Temp.	$T_A = T_{low}$ to T_{high}	<u> </u>	5	_	_	5	_	%
Vosc	Oscillator Voltage Swing	(peak to peak)	-	1.6	_	_	1.6	_	V
I _{dischg}	Discharge Current (V _{OSC} =2V)	T _J = 25°C	7.8	8.3	8.8	7.8	8.3	8.8	mA
ERROR A	MP SECTION		•	,		,	,	,	
V ₂	Input Voltage	V _{PIN1} = 2.5V	2.45	2.50	2.55	2.42	2.50	2.58	V
I _b	Input Bias Current	$V_{FB} = 5V$		-0.1	-1		-0.1	-2	μΑ
	A _{VOL}	$2V \le V_0 \le 4V$	65	90		65	90		dB
BW	Unity Gain Bandwidth	T _J = 25°C	0.7	1		0.7	1		MHz
PSRR	Power Supply Rejec. Ratio	$12V \leq V_i \leq 25V$	60	70		60	70		dB
I _o	Output Sink Current	V _{PIN2} = 2.7V V _{PIN1} = 1.1V	2	12		2	12		mA
I _o	Output Source Current	V _{PIN2} = 2.3V V _{PIN1} = 5V	-0.5	-1		-0.5	-1		mA
105	V _{OUT} High	V_{PIN2} = 2.3V; R_L = 15K Ω to Ground	5	6.2		5	6.2		V
, -	Vout Low	V_{PIN2} = 2.7V; R_L = 15K Ω to Pin 8		0.8	1.1		0.8	1.1	V
CURREN	T SENSE SECTION		•	,		,	,	,	
G _V	Gain	(note 3 & 4)	2.85	3	3.15	2.85	3	3.15	V/V
V ₃	Maximum Input Signal	V _{PIN1} = 5V (note 3)	0.9	1	1.1	0.9	1	1.1	V
SVR	Supply Voltage Rejection	$12 \le V_i \le 25V$ (note 3)		70			70		dB
I _b	Input Bias Current			-2	-10		-2	-10	μΑ
	Delay to Output			150	300		150	300	ns

Table 5. Electrical Characteristcs (continued)

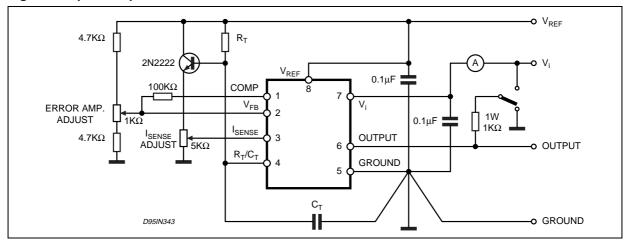
([note 1] Unless otherwise stated, these specifications apply for -25 < T_{amb} < 85°C for UC284XA; $0 < T_{amb} < 70$ °C for UC384XA; $V_i = 15V$ (note 5); $R_T = 10K$; $C_T = 3.3nF$)

Comple ed	Domenter	Test Condition	U	C284X	Α	U	C384X	Α	Unit	
Symbol Parameter		Mi		Тур.	Max.	Min.	Тур.	Max.	Unit	
OUTPUT	OUTPUT SECTION									
VoL	Output Low Level	I _{SINK} = 20mA		0.1	0.4		0.1	0.4	V	
		I _{SINK} = 200mA		1.6	2.2		1.6	2.2	V	
Voн	Output High Level	I _{SOURCE} = 20mA	13	13.5		13	13.5		V	
		I _{SOURCE} = 200mA	12	13.5		12	13.5		V	
V _{OLS}	UVLO Saturation	V _{CC} = 6V; I SINK = 1mA		0.7	1.2		0.7	1.2	V	
t _r	Rise Time	$T_j = 25^{\circ}C$ $C_L = 1nF^{(2)}$		50	150		50	150	ns	
t _f	Fall Time	$T_j = 25^{\circ}C$ $C_L = 1nF^{(2)}$		50	150		50	150	ns	
UNDER-V	OLTAGE LOCKOUT SECTION	ON								
	Start Threshold	X842A/4A	15	16	17	14.5	16	17.5	V	
		X843A/5A	7.8	8.4	9.0	7.8	8.4	9.0	>	
	Min Operating Voltage After Turn-on	X842A/4A	9	10	11	8.5	10	11.5	٧	
PWM SE	CTION		•	40			•			
	Maximum Duty Cycle	X842A/3A	94	96	100	94	96	100	%	
		X844A/5A	47	48	50	47	48	50	%	
	Minimum Duty Cycle	- 103)		0			0	%	
TOTAL S	TOTAL STANDBY CURRENT									
I _{st}	Start-up Current	V _i = 6.5V for UCX843A/ 45A		0.3	0.5		0.3	0.5	mA	
		V _i = 14V for UCX842A/44A		0.3	0.5		0.3	0.5	mA	
lį	Operating Supply Current	V _{PIN2} = V _{PIN3} = 0V		12	17	_	12	17	mA	
V _{iz}	Zener Voltage	$I_i = 25 \text{mA}$	30	36		30	36		V	

Notes: 1. Max package power dissipation limits must be respected; low duty cycle pulse techniques are used during test maintain Ti as close to T_{amb} as possible.

- 2. These parameters, although guaranteed, are not 100% tested in production.
- Parameter measured at trip point of latch with V_{PIN2} = 0.
 Gain defined as : A = ΔV_{PIN1}/ΔV_{PIN3}; 0 ≤ V_{PIN3} ≤ 0.8V
- 5. Adjust V_i above the start threshold before setting at 15 V.

Figure 4. Open Loop Test Circuit.



High peak currents associated with capacitive loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to pin 5 in a single point ground. The transistor and 5 K Ω potentiometer are used to sample the oscillator waveform and apply an adjustable ramp to pin 3.

Figure 5. Oscillator Frequency vs Timing Resistance

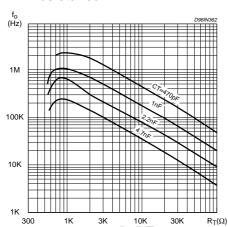


Figure 6. Maximum Duty Cycle vs Timing Resistor

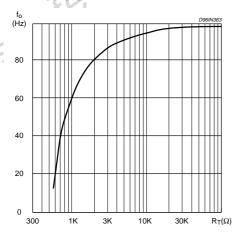


Figure 7. Oscillator Discharge Current vs. Temperature.

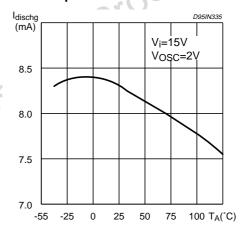


Figure 8. Error Amp Open-Loop Gain and Phase vs. Frequency.

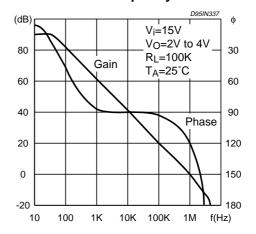


Figure 9. Current Sense Input Threshold vs. Error Amp Output Voltage.

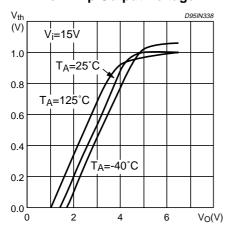


Figure 10. Reference Voltage Change vs. Source Current..

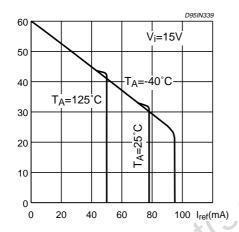


Figure 11. Reference Short Circuit Current vs. Temperature..

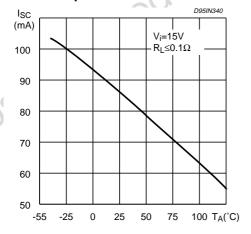


Figure 12. Output Saturation Voltage vs. Load Current.

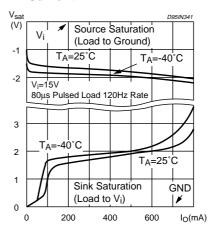


Figure 13. Supply Current vs. Supply Voltage.

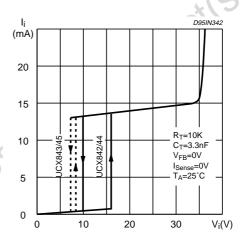


Figure 14. Output Waveform.

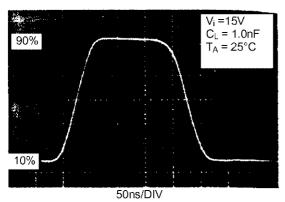


Figure 15. Output Cross Conduction

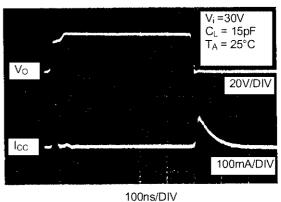


Figure 16. Oscillator and Output Waveforms.

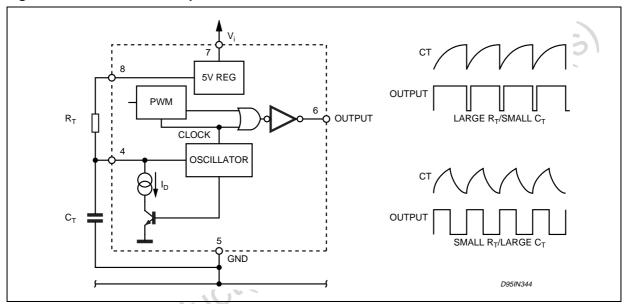


Figure 17. Error Amp Configuration.

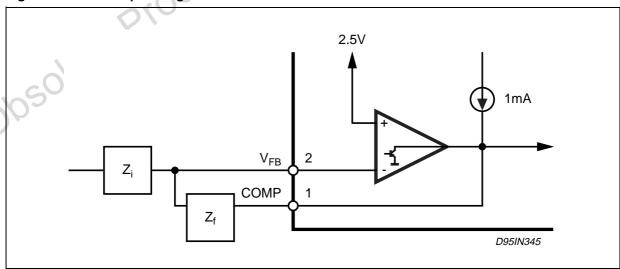


Figure 18. Under Voltage Lockout.

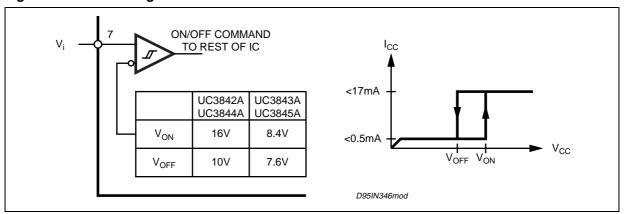
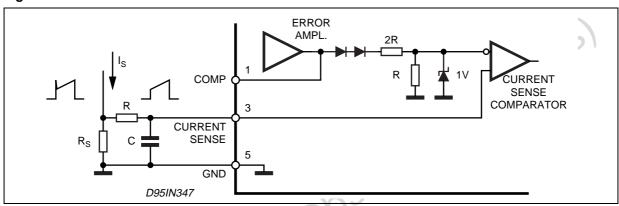


Figure 19. Current Sense Circuit.

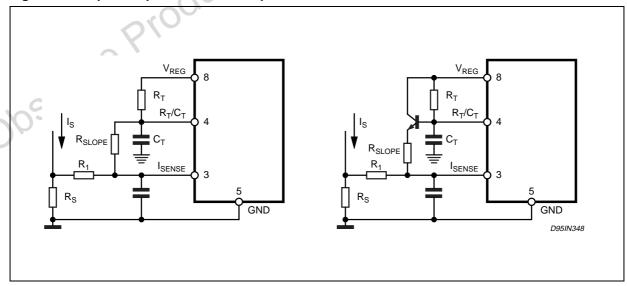


Peak current (is) is determined by the formula

$$I_{Smax} \approx \frac{1.0V}{R_S}$$

A small RC filter may be required to suppress switch transients.

Figure 20. Slope Compensation Techniques.



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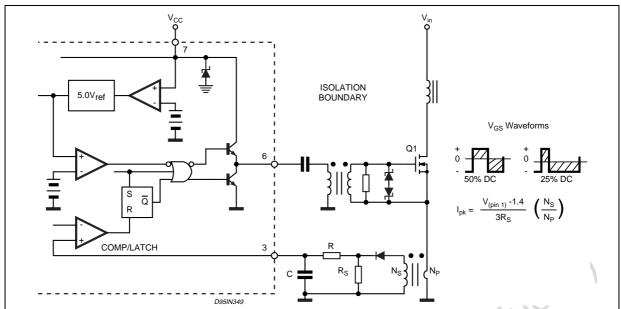


Figure 21. Isolated MOSFET Drive and Current Transformer Sensing.

Figure 22. Latched Shutdown.

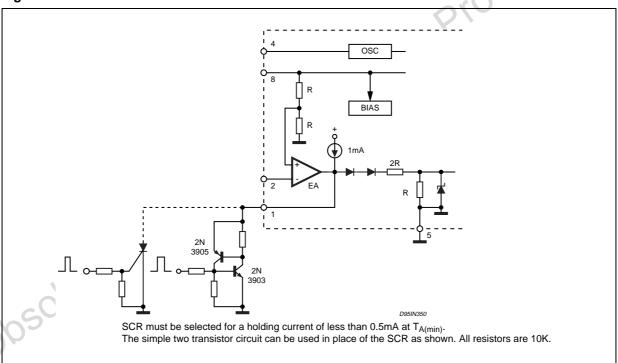


Figure 23. Error Amplifier Compensation

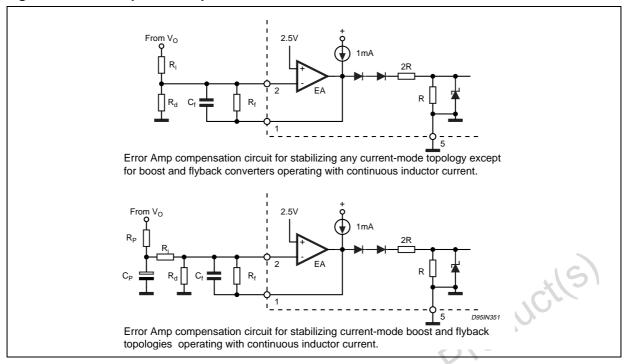
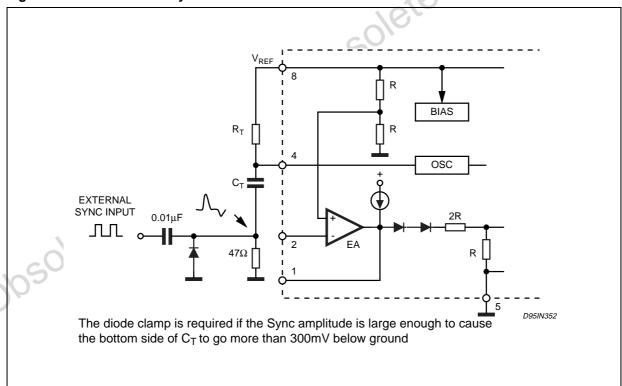


Figure 24. External Clock Synchronization.



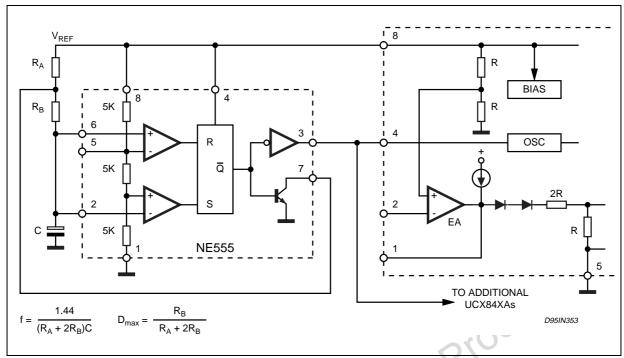
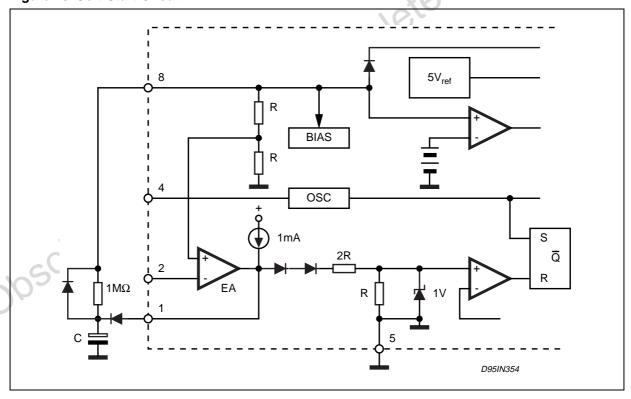


Figure 25. External Duty Cycle Clamp and Multi Unit Synchronization.

Figure 26. Soft-Start Circuit



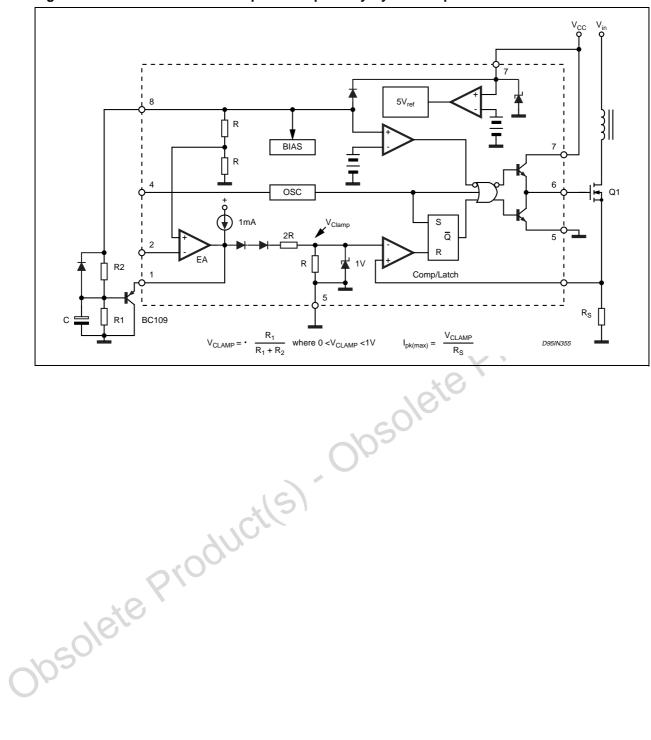


Figure 27. Soft-Start and Error Amplifier Output Duty Cycle Clamp.

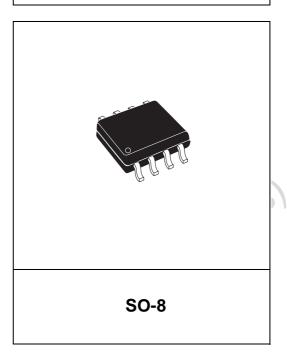
Figure 28. SO-8 Mechanical Data & Package Dimensions

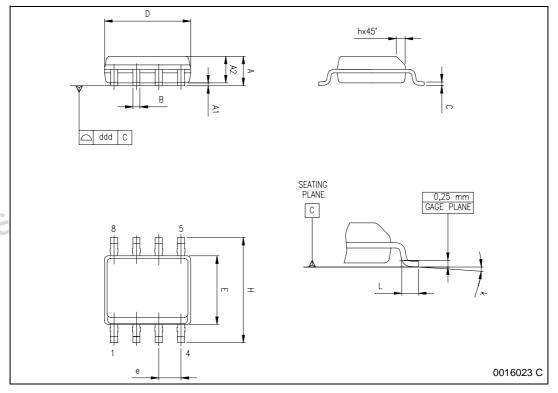
DIM.		mm			inch	
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D ⁽¹⁾	4.80		5.00	0.189		0.197
Е	3.80		4.00	0.15		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	0° (min.), 8° (max.)					
ddd			0.10			0.004

Note: (1) Dimensions D does not include mold flash, protrusions or gate burrs.

Mold flash, potrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

OUTLINE AND MECHANICAL DATA



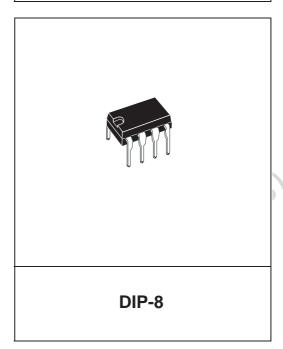


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Figure 29. DIP-8 Mechanical Data & Package Dimensions

DIM.	mm				inch		
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
Е	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0.260	
I			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	

OUTLINE AND MECHANICAL DATA



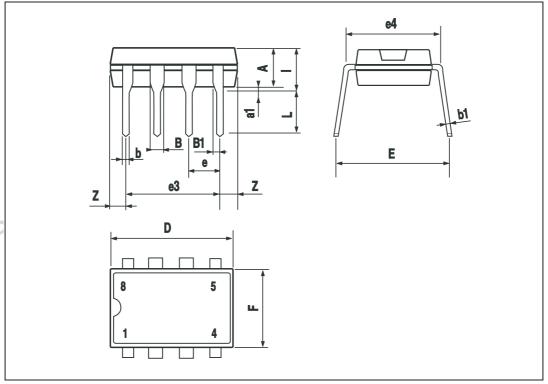


Table 6. Revision History

Date	Revision	Description of Changes
March 1999	4	First Issue in EDOCS
May 2004	5	NOT FOR NEW DESIGN

Obsolete Product(s). Obsolete Product(s)

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